

ACADEMICIAN

STEPAN KHOREN ESSAIAN



CURRICULUM VITAE

Dr. Stepan Essaian is founder, President and CTO of SPECTRALUS Inc. and has over 20 years of experience in solid-state optoelectronics, physics and technology of semiconductor devices, telecommunications systems and networks.

In USA Dr. Essaian started his carrier as a Visiting Professor by invitation of Rutgers University: from December 1991 and August 1994 he became US Permanent Resident by receiving Green Card as a Scientist with extraordinary achievements.

From May 2000 to December 2002, Dr. Essaian serves as the Chief Scientist for Solid State Photonix/Teraburst Networks Co, a leading developer of an OMO analog switch for OXCs. Prior to working at SSP, Dr. Essaian directed the development of SiGe-based technology used in the wireless and networking marketplace at National Semiconductor Co. Before National Semiconductor, he served as a Visiting Professor at the Department of Material Science of Rutgers University. Before emigration to the US, Dr. Essaian worked as a Senior Scientist at A.F. Ioffe Physico-Technical Institute in St.-Petersburg, Russia, and as Visiting Professor of Optics at Yerevan State University, Armenia, where he carried out research work in the field of acousto-optic, electro-optic, photo-refractive and nonlinear-optic effects in dielectrics and semiconductor materials. Dr. Essaian is an author of over 100 publications and he holds 12 patents in the field of advanced materials and processes and optical-related technologies. In addition, he has 5 patents-pending on optical switching and the PPLN/PPLT technology.

Educations:

MS in Semiconductor Physics and Technology; Yerevan State Engineering University, Armenia

PhD in Solid State Physics , A.F. Ioffe Physico-Technical Institute, St.-Petersburg, Russia

Sc.D in Solid State Physics, A.F. Ioffe Physico-Technical Institute, St.-Petersburg, Russia

Related publications:

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